

Metallic and Ceramic Coatings for Medical Devices Deposited by Vacuum Based Methods

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Meet&Match Surface Technologies for Medical Devices

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Content

Vacuum Based Deposition

PVD, IBAD, MS, CVD, PE-CVD

CrNx-coatings by IBAD

Influence of Ion Beam Parameters on coating properties

TiO₂-coatings by Magnetron Sputtering

Influence of pulse mode on morphology and cristallinity

Zn-based bioabsorbable alloys

Oxide layer densification by annealing in oxygen plasma

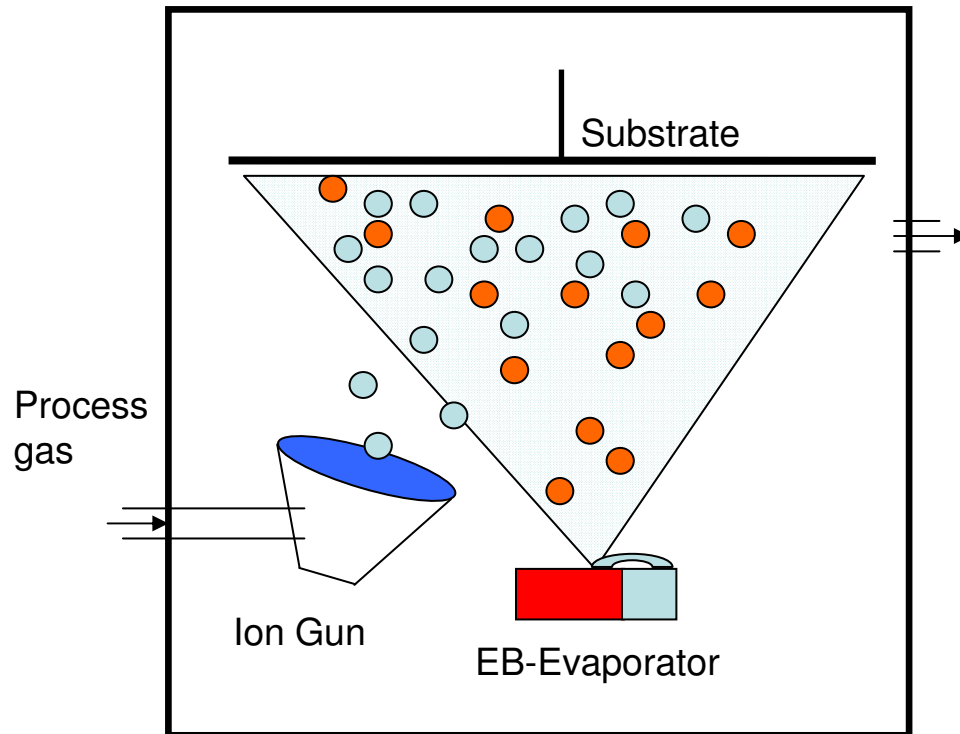
Si₃N₄-coatings by PE-CVD

Influence of frequency on internal stress

Physical Vapor Deposition (PVD)

Thermal Evaporation

Ion Beam Assisted Deposition (IBAD)



Evaporation

Electron Beam or
electrical
resistance heating

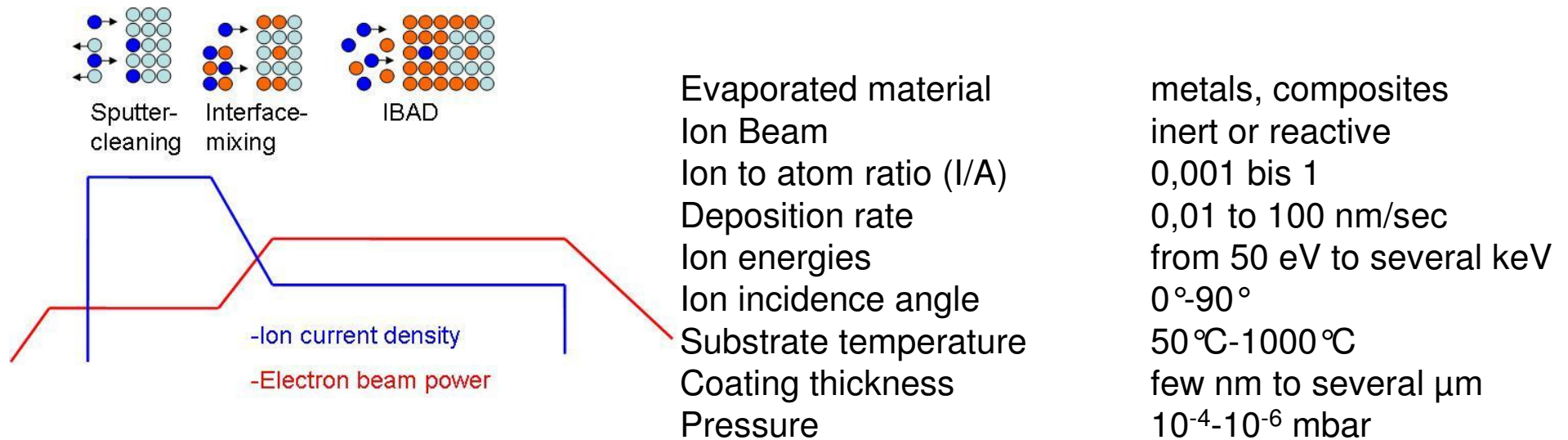
Ion Beams

Sputter cleaning,
Reactive process

Coating
densification



Ion Beam Assisted Deposition (IBAD)

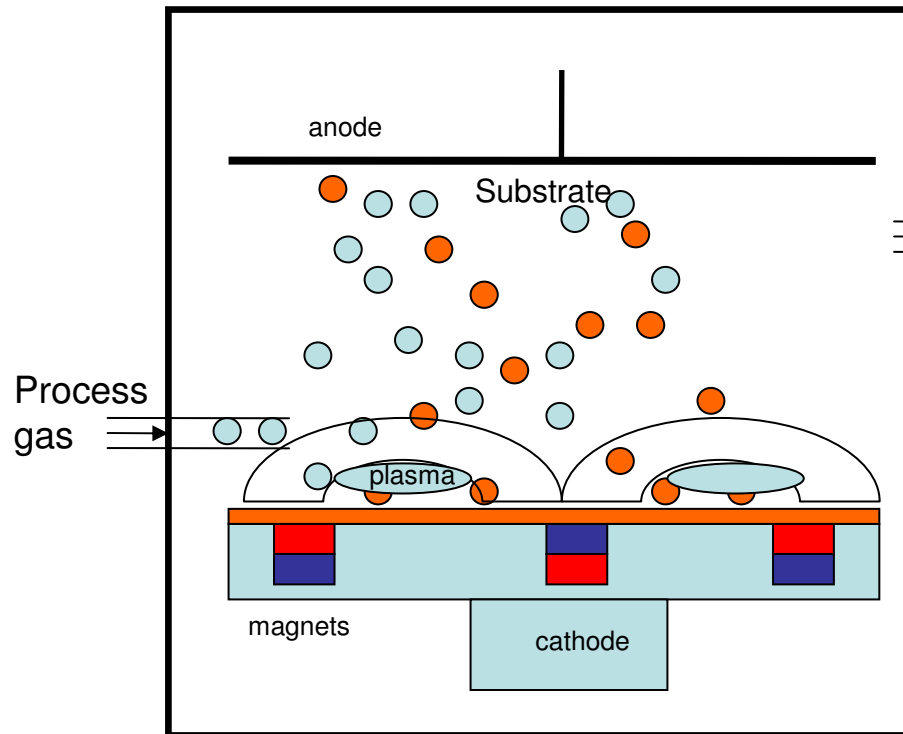


Parameter variation influences

Coating composition, Crystallinity/Texture, Morphology, Porosity, Internal stress, hardness, Adhesion, Corrosion resistance, Wear resistance, Friction

PVD

Magnetron Sputtering



DC-Sputtering

Voltage applied between anode (substrate) and cathode (target)

RF-Sputtering

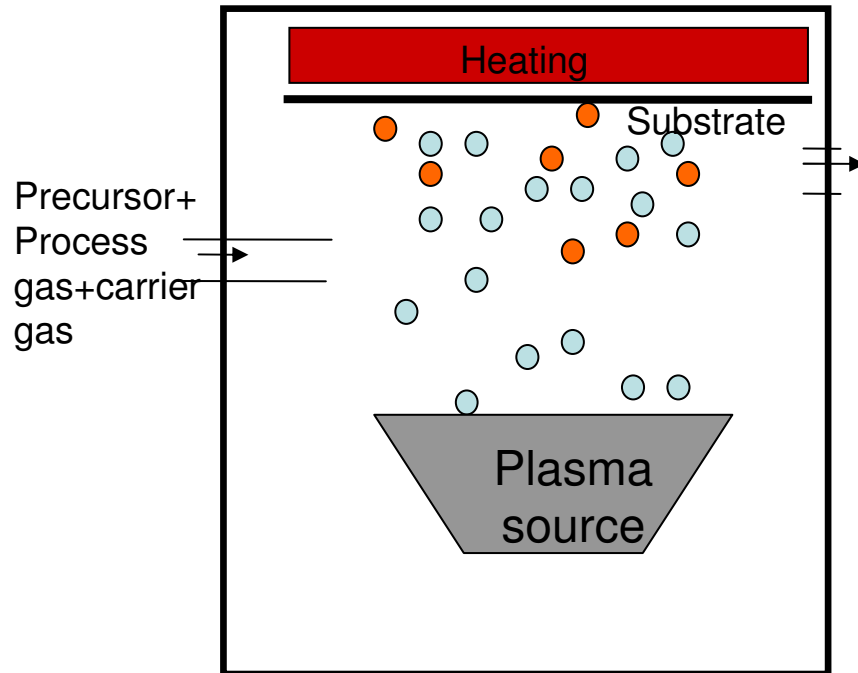
Plasma through high frequency input
(13,56/27,12MHz)



Pulsed DC-MS: Unipolar/bipolar

High-power Impulse Magnetron Sputtering (HIPIMS)

Chemical Vapor Deposition (CVD)



CVD hot substrate (500-1000 °C) is exposed to one or more volatile precursors

PE-CVD plasma enhancement allows lower substrate temperatures (200-500 °C)

Coating	Precursor
Si ₃ N ₄	SiH ₄ + N ₂
SiC	Trimethyl silane
SiO ₂	SiH ₄ + O ₂ /TMSO + O ₂
TiO ₂	Titanium 2-propoxide
DLC	CH ₄ /C ₂ H ₂ /H ₂

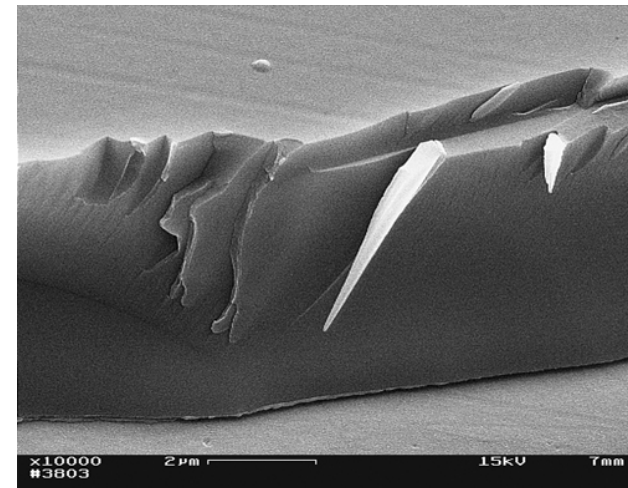
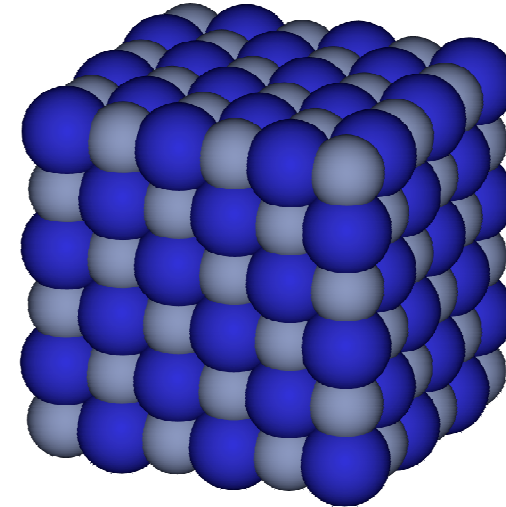
Ion Beam Assisted Deposition (IBAD)

CrN-coatings

- High Hardness
- Improved wear resistance, low friction
- Creates a chemically inert barrier
- Improves corrosion resistance
- Higher temperature resistance than TiN
- Uniform, metallic silver appearance over repeated autoclaving cycles

Applications:

Surgical tools like scissors, saws, drills



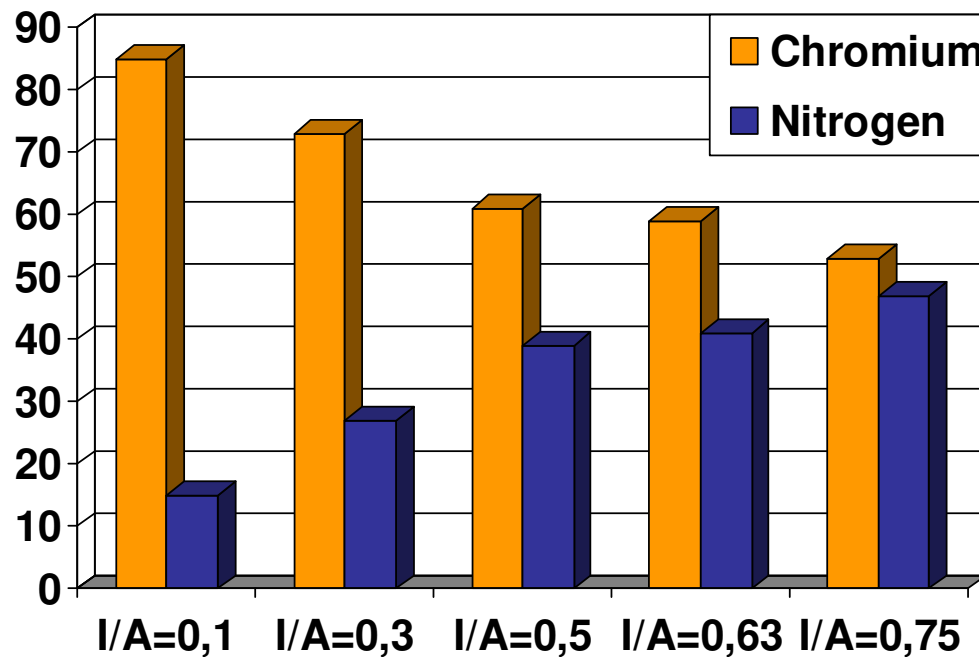
Ion Beam Assisted Deposition (IBAD)

CrNx-coatings, Influence of I/A to composition

$$\frac{I}{A} = \frac{j}{R} \cdot \frac{M_m}{Ne\rho}$$

j : ion current, R : deposition rate, M_m : molecular mass,

N : Avogadro constant, e : elementary charge, ρ : density



Ion energy: 500eV

Ion incident angle: 20°

No substrate heating

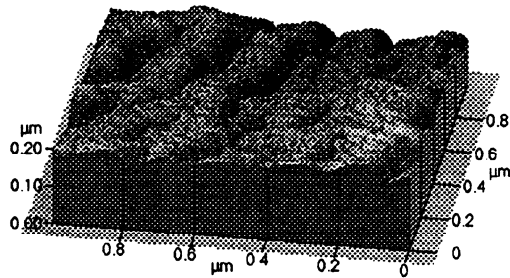
→ gradient layers

Substrate – Cr- CrN

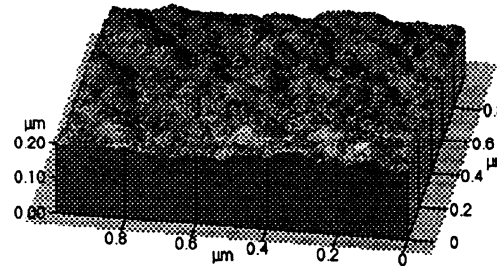
In case of very different
thermal expansion
coefficients of substrate and
CrN

Ion Beam Assisted Deposition (IBAD)

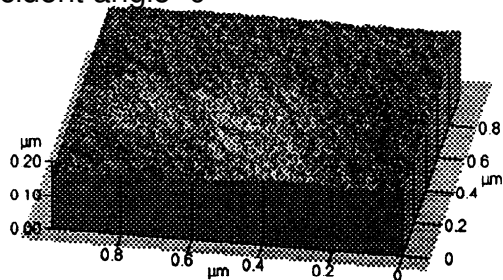
CrNx-coatings, Influence of ion incidence angle on surface morphology



Ion incident angle 0°



Ion incident angle 30°

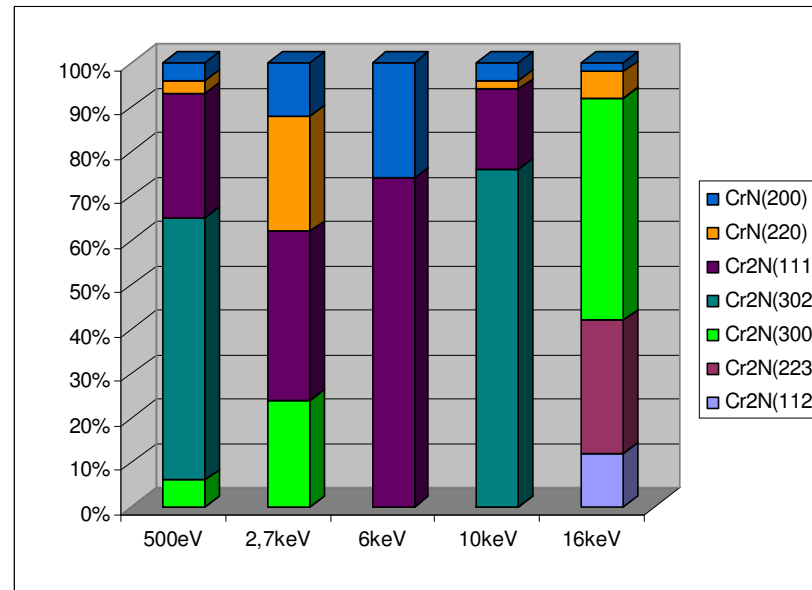
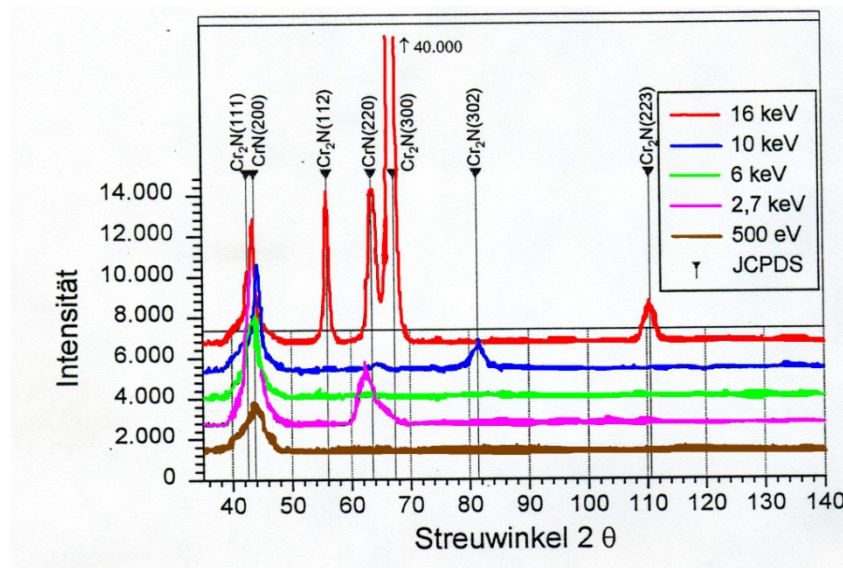


Ion incident angle 60°

Ion energy: 500eV
Ion current density: 120μA/cm²
I/A: 0,5
No substrate heating

Ion Beam Assisted Deposition (IBAD)

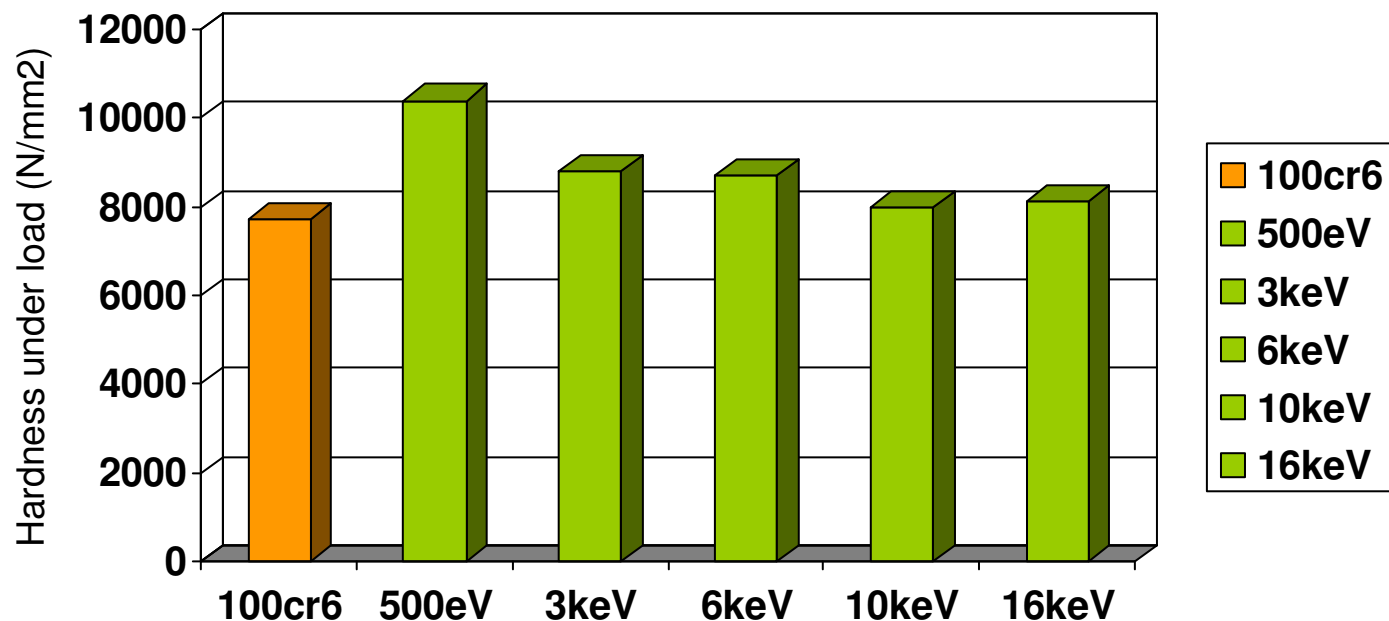
CrNx-coatings, Influence of ion energy on composition and cristallinity



Ion incidence angle: 0°
I/A: 0,5
No substrate heating

Ionenstrahlunterstützte Abscheidung (IBAD)

CrNx-coatings, Influence of ion energy to micro hardness



Ion incidence angle :

0°

I/A:

0,5

Coating thickness:

1,4µm

No substrate heating

PVD-Magnetron Sputtering

Photocatalytic TiO₂-coatings

Hospital Acquired Infections (HAI)

- are still widespread (estimated annually 400T-900T in Germany)
- cause a high morbidity (10T-30T annually in Germany*) and
- high costs (annually 10 Billion US\$ in the USA)
- About half of the nosocomial infections are device related infections (DRI) associated with indwelling devices like short term implants and prosthetic implants

Antimicrobial surfaces help to reduce DRI

Photocatalytic TiO₂-surfaces are antimicrobial, biocompatible, easy to realize and cheap.

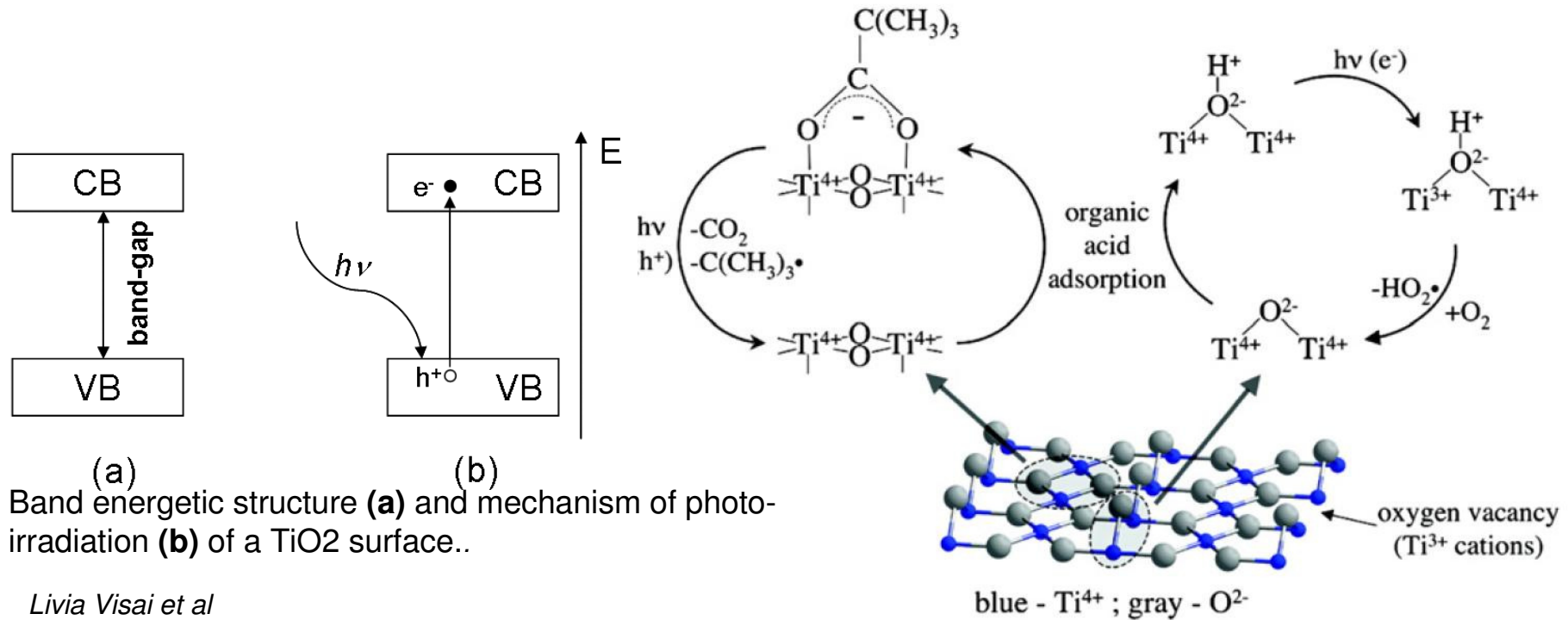
*P. Gastmeier, Nosokomiale Infektionen in Deutschland and

Deutsche Ges. f. Krankenhaushygiene, Bis zu 30.000 Tote jährlich durch Krankenhausinfektionen



PVD-Magnetron Sputtering

Photocatalytic TiO₂-coatings



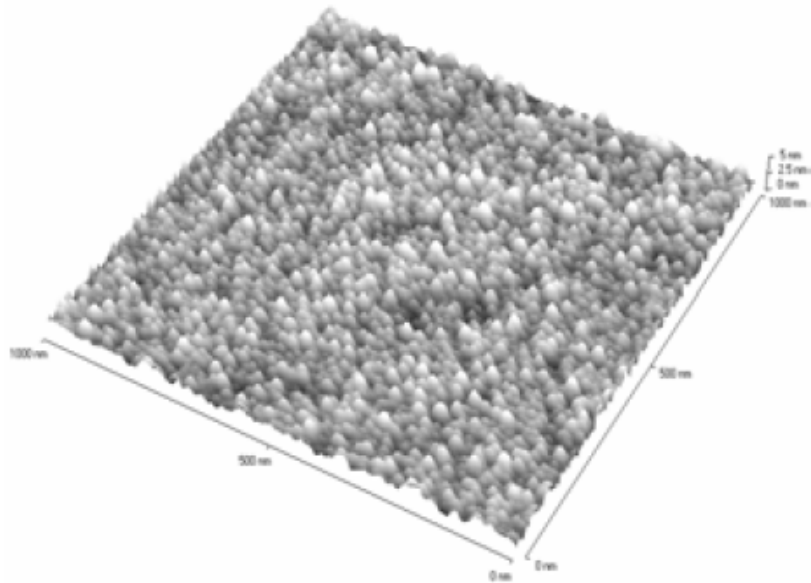
Band energetic structure **(a)** and mechanism of photo-irradiation **(b)** of a TiO₂ surface..

Livia Visai et al

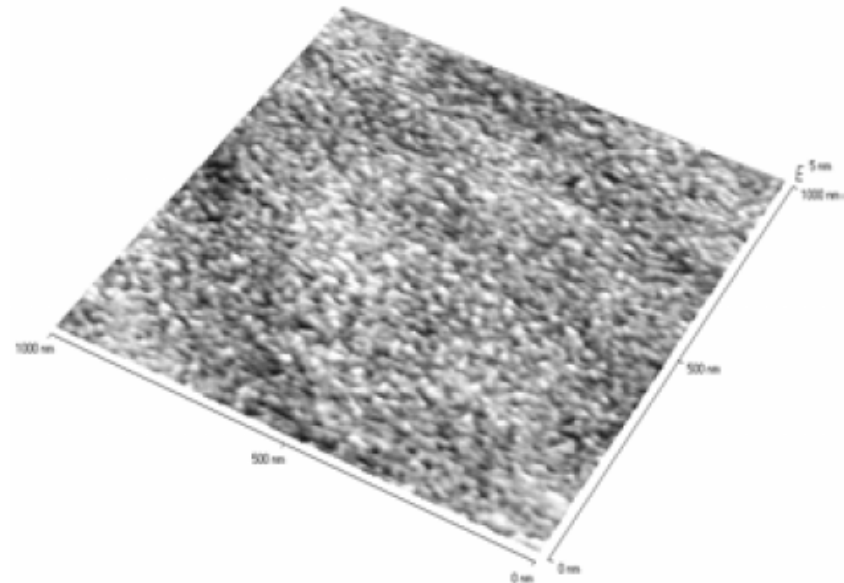
Reaction scheme for both redox processes associated with photodecomposition of trimethyl acetic acid (TMAA) on a TiO₂-surface

PVD-Magnetron Sputtering

Photocatalytic TiO_2 -coatings



Unipolar mode, 10 kW
 $R_a=0,48$ nm

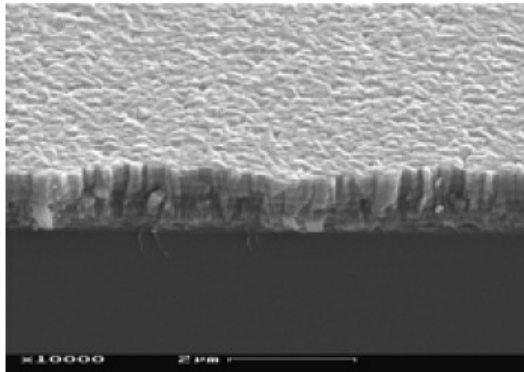


Bipolar mode, 10 kW
 $R_a=0,20$ nm

PVD-Magnetron Sputtering

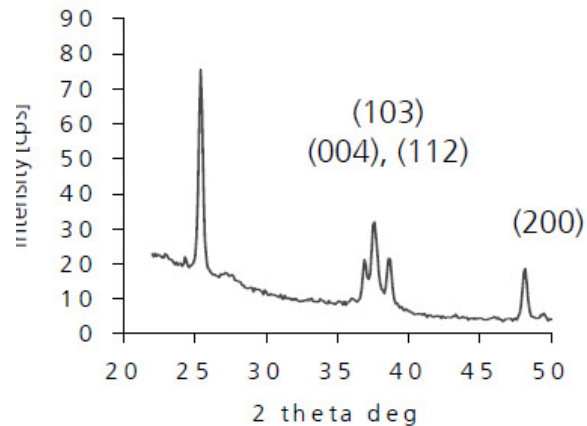
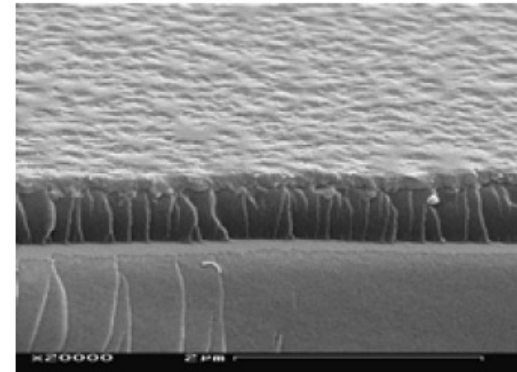
Photocatalytic TiO_2 -coatings

Influence of sputtering mode on cristallinity

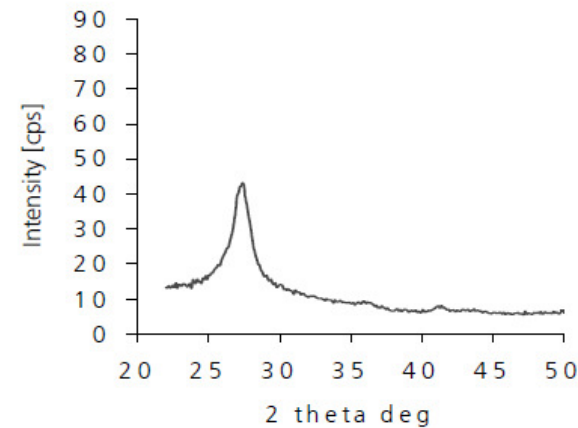


FEP

Dresden



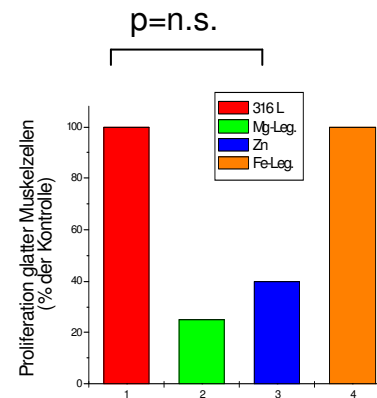
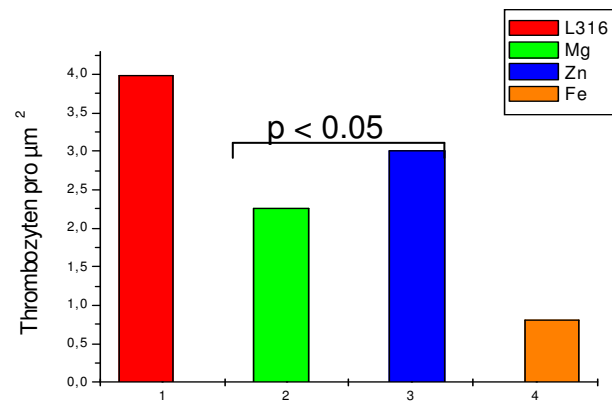
Unipolar mode, 10 kW



Bipolar mode, 10 kW

Plasma Modifications

Photocatalytic ZnO-coatings on bioabsorbable zink alloys



Oxide layer treatment of the native oxide layer using O_2 -plasmas+annealing

→ Prolongued bioabsorption times through densification of the protective oxide layer

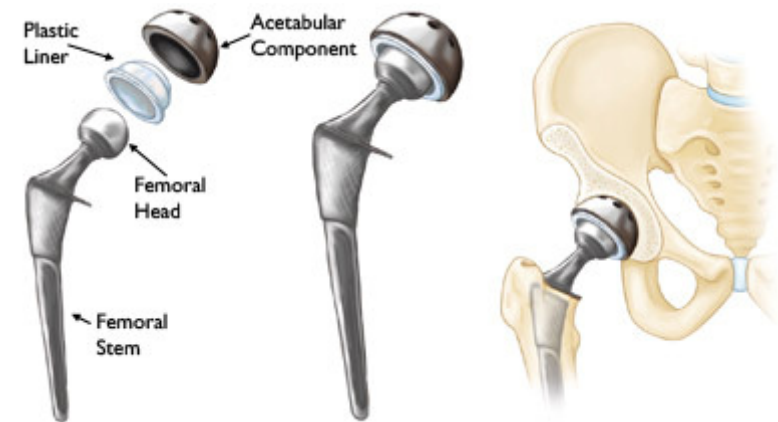
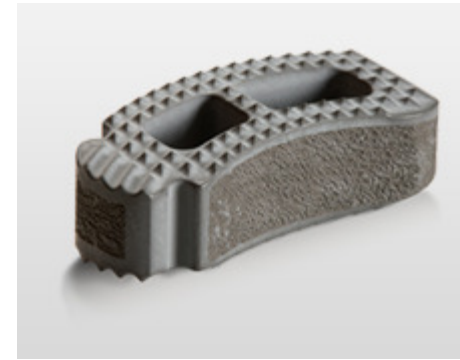
→ Cristallization resulting in enhanced photocatalytic activity

Plasma Enhanced Chemical Vapor Deposition

Si_3N_4 -coatings

Si_3N_4 spinal implant for interbody fusion
Potential material for femoral head in total hip joint replacements

excellent biocompatibility,
low wear rates
relatively high fracture toughness and strength



Plasma Enhanced Chemical Vapor Deposition

Si_3N_4 Silane and Ammonia/ N_2

Advantages:

- Coating deposition starting at 250 °C
- High quality, pinhole-free coatings can be achieved
- High deposition rates (500nm/min)

Disadvantages:

- H_2 can be integrated into the coatings → less dense coatings
- incorporated H_2 can diffuse to the interface and deteriorate the substrate

Plasma Enhanced Chemical Vapor Deposition

Parameter variation

- Gas flows, gas supply geometry
- Plasma parameters like power, plasma gas
- Pressure
- Substrate temperature

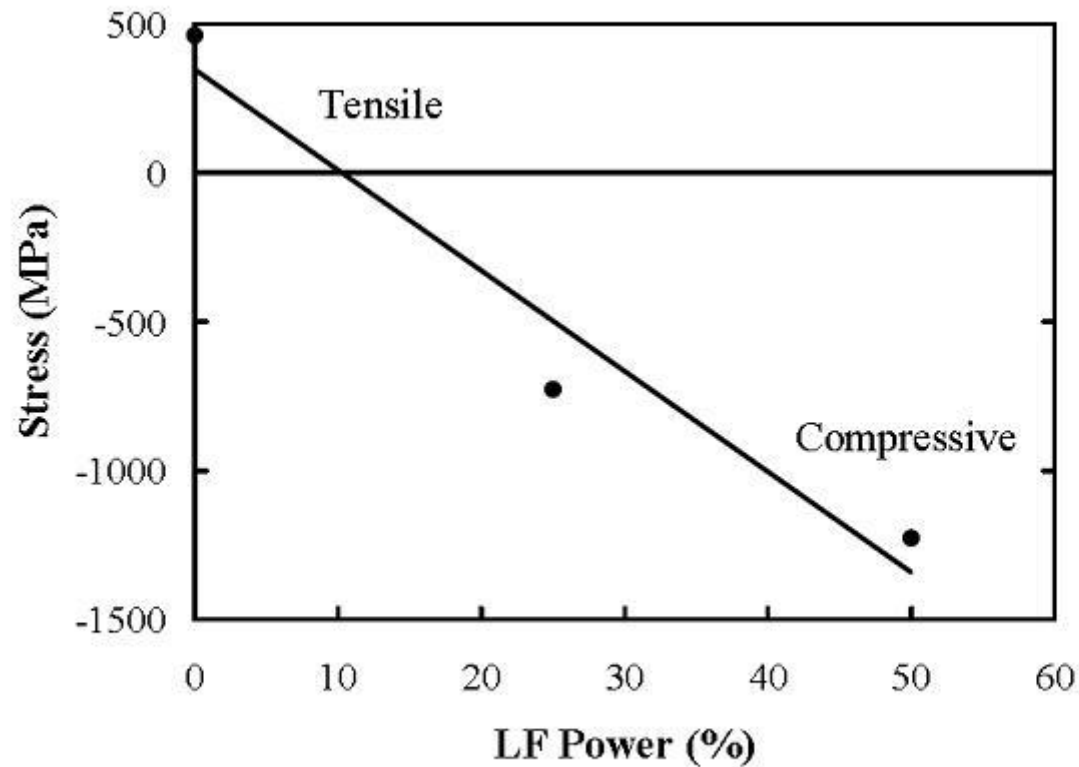
e.g:

- Plasma power and temperature increase, pressure reduction (Huang et al)
→ Increase of hardness + E-Modulus

Or:

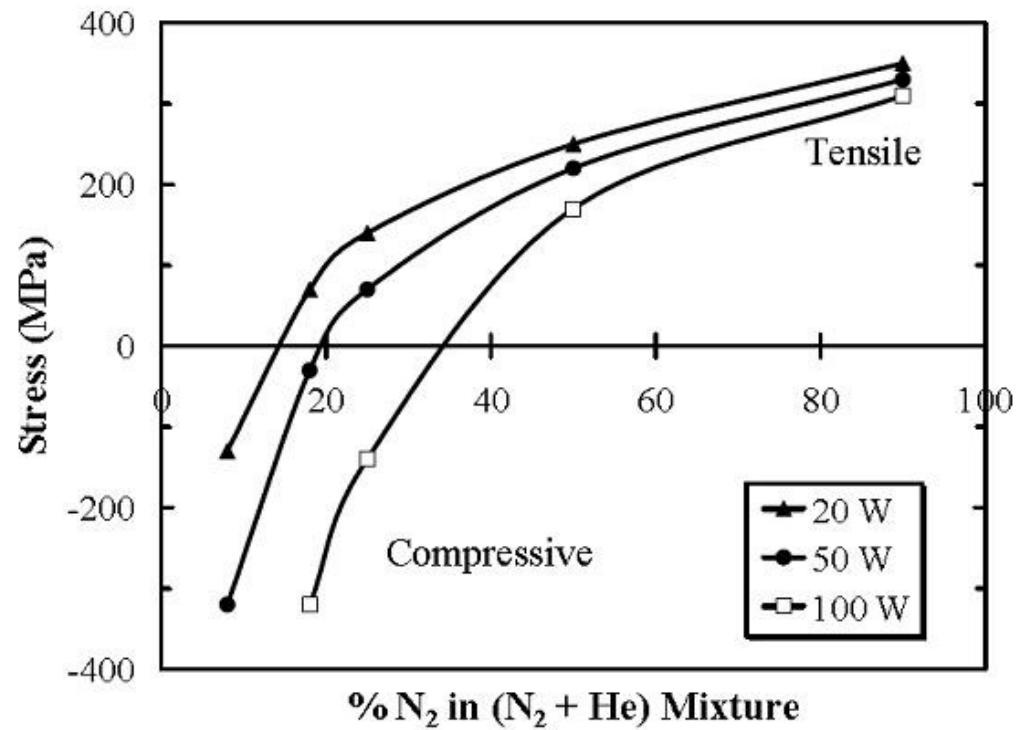
- Dual frequency PE-CVD: Overlap of two microwave frequencies (13,6 MHz and 340kHz)
→ Control of the intrinsic stress

Plasma Enhanced Chemical Vapor Deposition



Si_3N_4 : Influence of an additional frequency to intrinsic stress
(Mackenzie et al)

Plasma Enhanced Chemical Vapor Deposition



Si₃N₄: Influence of plasma power and helium addition on intrinsic stress

Thank you

Danke

Merci

